Product data sheet

1. General description

Ultrafast power diode in a SOD141 (DO-201AD) axial lead plastic package.

2. Features and benefits

- Axial leaded plastic package
- Fast switching
- High voltage capability
- Low forward voltage drop
- Low leakage current
- Low thermal resistance
- Soft recovery characteristic

3. Applications

- Discontinuous Current Mode (DCM) Power Factor Correction (PFC)
- · High frequency switched-mode power supplies

4. Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V_{RRM}	repetitive peak reverse voltage		-	-	600	V
I _{F(AV)}	average forward current	δ = 0.5; square-wave pulse; Fig. 1; Fig. 2	-	-	4	А
Static characte	eristics					
V _F	forward voltage	I _F = 3 A; T _j = 150 °C; <u>Fig. 4</u>	-	0.82	1.05	V
Dynamic chara	acteristics					
t _{rr}	reverse recovery time	I_F = 1 A; V_R = 30 V; dI_F/dt = 100 A/µs; T_j = 25 °C; Ramp Recovery; Fig. 5	-	35	-	ns
		$I_R = 1 \text{ A}; I_F = 0.5 \text{ A}; I_{R(meas)} = 0.25 \text{ A};$ $T_j = 25 \text{ °C}; \text{ Step Recovery}; Fig. 6$	-	-	50	ns





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5. Pinning information

Table 2. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	K	cathode	k a	K — A
2	Α	anode	DO-201AD (SOD141)	001aaa020

6. Ordering information

Table 3. Ordering information

Type number	Package		
	Name	Description	Version
NUR460P	DO-201AD	Hermetically sealed plastic package; axial leaded; 2 leads	SOD141
NUR460P/L01	DO-201AD	Hermetically sealed plastic package; axial leaded; 2 leads	SOD141
NUR460P/L02	DO-201AD	Hermetically sealed plastic package; axial leaded; 2 leads	SOD141
NUR460P/L03	DO-201AD	Hermetically sealed plastic package; axial leaded; 2 leads	SOD141
NUR460P/L04	DO-201AD	Hermetically sealed plastic package; axial leaded; 2 leads	SOD141
NUR460P/L05	DO-201AD	Hermetically sealed plastic package; axial leaded; 2 leads	SOD141
NUR460P/L06	DO-201AD	Hermetically sealed plastic package; axial leaded; 2 leads	SOD141
NUR460P/L07	DO-201AD	Hermetically sealed plastic package; axial leaded; 2 leads	SOD141

7. Marking

Table 4. Marking codes

Type number	Marking code
NUR460P	NXPNUR460P
NUR460P/L01	
NUR460P/L02	
NUR460P/L03	
NUR460P/L04	
NUR460P/L05	
NUR460P/L06	
NUR460P/L07	

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8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
V_{RRM}	repetitive peak reverse voltage		-	600	V
V_{RWM}	crest working reverse voltage		-	600	V
V _R	reverse voltage	DC	-	600	V
I _{F(AV)}	average forward current	$\bar{\delta}$ = 0.5; square-wave pulse; Fig. 1; Fig. 2	-	4	A
I _{FRM}	repetitive peak forward current	δ = 0.5 ; t_p = 25 µs; square-wave pulse	-	8	Α
I _{FSM}	non-repetitive peak forward current	t_p = 10 ms; $T_{j(init)}$ = 25 °C; sine-wave pulse; Fig. 3	-	100	A
		t_p = 8.3 ms; $T_{j(init)}$ = 25 °C; sine-wave pulse; Fig. 3	-	110	A
T _{stg}	storage temperature		-65	175	°C
Tj	junction temperature		-	175	°C

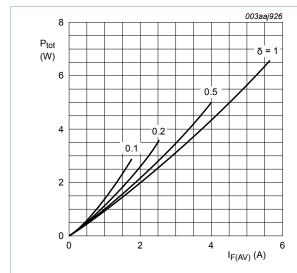


Fig. 1. Forward power dissipation as a function of average forward current; square waveform; maximum values

$$\begin{split} I_{F(AV)} &= I_{F(RMS)} \times \sqrt{\delta} \\ V_{O} &= 0.947 \text{ V; } R_{S} = 0.037 \text{ } \Omega \end{split}$$

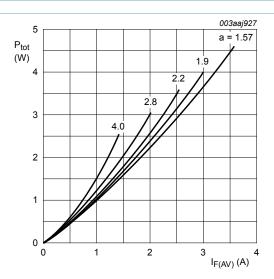
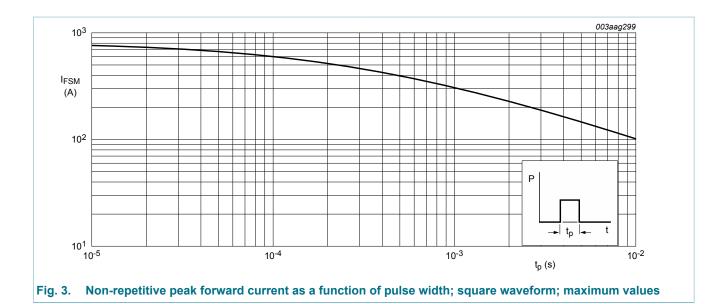


Fig. 2. Forward power dissipation as a function of average forward current; sinusoidal waveform; maximum values

a = form factor =
$$I_{F(RMS)}/I_{F(AV)}$$

 $V_O = 0.947 \text{ V}; R_S = 0.037 \Omega$

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9. Thermal characteristics

Table 6. Thermal characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
R _{th(j-a)}	thermal resistance from junction to ambient	in free air	-	55	-	K/W

10. Characteristics

Table 7. Characteristics

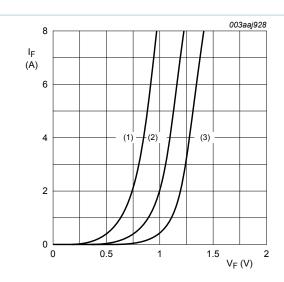
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static chara	acteristics			'		
V_{F}	forward voltage	I _F = 3 A; T _j = 25 °C; <u>Fig. 4</u>	-	-	1.25	V
		I _F = 3 A; T _j = 150 °C; <u>Fig. 4</u>	-	0.82	1.05	V
		I _F = 4 A; T _j = 25 °C; <u>Fig. 4</u>	-	-	1.28	V
I _R	reverse current	V _R = 600 V; T _j = 25 °C	-	-	10	μΑ
		V _R = 600 V; T _j = 150 °C	-	-	250	μA
Dynamic ch	haracteristics					
t _{rr}	reverse recovery time	I_F = 1 A; V_R = 30 V; dI_F/dt = 50 A/ μ s; T_j = 25 °C; Ramp Recovery; Fig. 5	-	-	75	ns
		$I_F = 1 \text{ A}; V_R = 30 \text{ V}; dI_F/dt = 100 \text{ A/µs};$ $T_j = 25 \text{ °C}; \text{Ramp Recovery}; \underline{\text{Fig. 5}}$	-	35	-	ns
		$I_F = 0.5 \text{ A}$; $I_R = 1 \text{ A}$; $I_{R(meas)} = 0.25 \text{ A}$; $I_{j} = 25 \text{ °C}$; Step Recovery; Fig. 6	-	-	50	ns

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(1) $T_j = 150$ °C; typical values; (2) $T_j = 150$ °C; maximum values; (3) $T_j = 25$ °C; maximum values; $V_O = 0.947$ V; $R_S = 0.037$ Ω

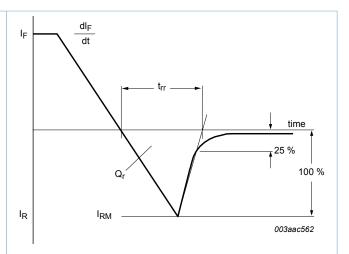


Fig. 5. Reverse recovery definitions; ramp recovery

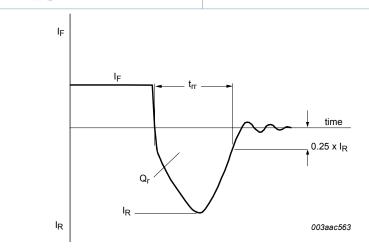
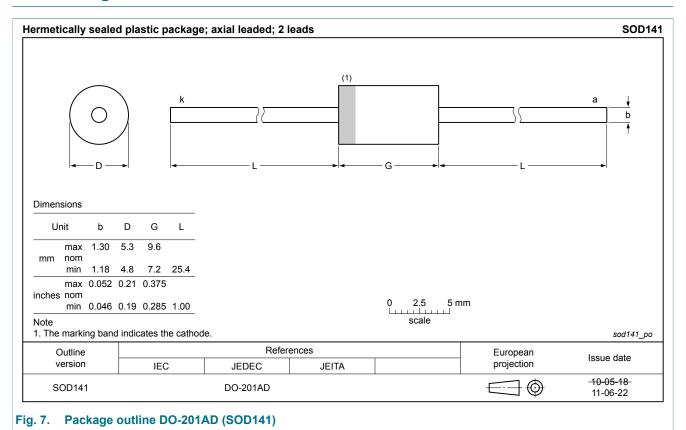


Fig. 6. Reverse recovery definitions; step recovery

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11. Package outline



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12. Legal information

12.1 Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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